





#### 150V NPN LED DRIVING TRANSISTOR IN SOT89

#### **Features**

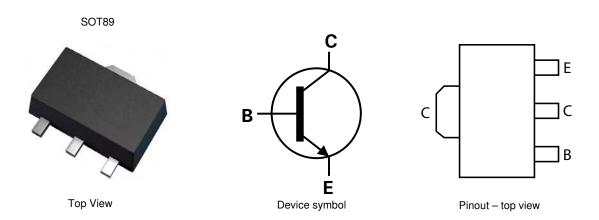
- BV<sub>CEO</sub> > 150V
- $h_{FE} > 100$  for  $I_C = 150$ mA,  $V_{CE} = 0.25$ V
- I<sub>C (cont)</sub> = 1A
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT-89
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.008 grams (Approximate)

#### **Applications**

LED TV backlight



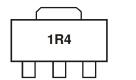
#### **Ordering Information**

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN10150DZTA	1R4	7	12	1000

Notes:

- 1. No purposefully added lead.
- 2. "Green" devices, Halogen and Antimony Free, Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

## **Marking Information**



1R4 - Product Type Marking Code





## **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	150	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current (Note 4)	I <sub>CM</sub>	3	Α
Base Current	I <sub>B</sub>	500	mA

## Thermal Characteristics @TA = 25°C unless otherwise specified

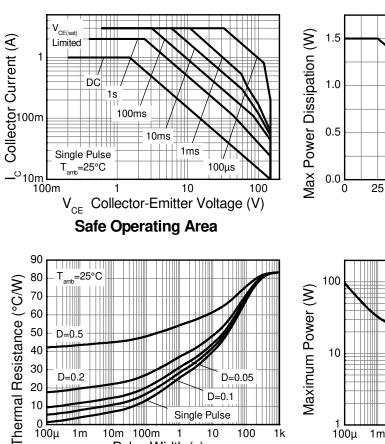
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	$P_{D}$	1.5	W
Thermal Resistance, Junction to Ambient (Note 3)	$R_{ heta JA}$	83	°C/W
Thermal Resistance, Junction to Leads	R <sub>θJL</sub>	6.36	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- 3. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions. 4. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ .



## **Thermal Characteristics and Derating information**



D=0.1

Single Pulse

Temperature (°C) **Derating Curve** Single Pulse Maximum Power (W)

75

100

125

150

175

50

100μ

**Transient Thermal Impedance** 

100m

Pulse Width (s)

Pulse Width (s) **Pulse Power Dissipation** 

100m

10

0 <del>---</del> 100μ





## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

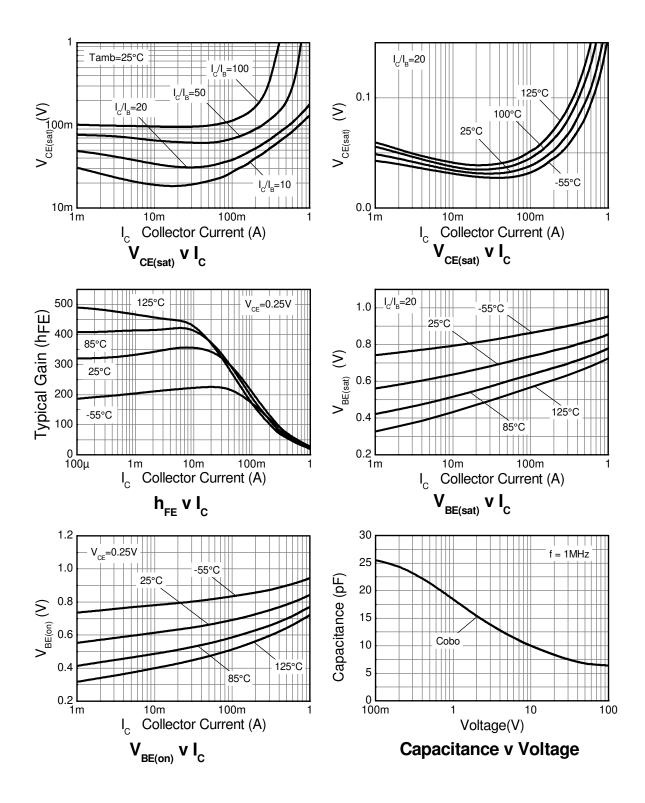
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	150	300	-	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 5)	BV <sub>CEO</sub>	150	175	-	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	$BV_EBO$	7	8.3	-	V	$I_E = 100 \mu A$
Collector Cut-off Current	I <sub>CBO</sub>	-	-	50	nA	V <sub>CB</sub> = 150V
Emitter Cut-off Current	I <sub>EBO</sub>	-	-	50	nA	$V_{EB} = 7V$
Obstitute Formand Comment Transfer Patitut (Nature F)		200	450	-		$I_{C} = 30 \text{mA}, V_{CE} = 5 \text{V}$
Static Forward Current Transfer Ratio (Note 5)	h <sub>FE</sub>	60 100	180 150	-	-	$I_C = 85\text{mA}, V_{CE} = 0.20\text{V}$ $I_C = 150\text{mA}, V_{CE} = 0.25\text{V}$
Base-Emitter Turn-On Voltage (Note 5)	V <sub>BE(on)</sub>	-	0.701	0.95	V	$I_C = 150 \text{mA}, V_{CE} = 0.25 \text{V}$
Output Capacitance	C <sub>OBO</sub>	-	10	-	рF	$V_{CB} = 10V$ , $f = 1MHz$
Current Gain-Bandwidth Product	ft	-	135	-	MHz	$V_{CB} = 10V$ , $Ic = 10mA$ , $f = 100MHz$
Delay Time	$t_{(d)}$	-	625	-	ns	
Rise Time	t <sub>(r)</sub>	-	562	-	ns	$V_{CC} = 110V, I_{C} = 150mA,$
Storage Time	$t_{(\mathtt{S})}$	-	2465	-	ns	$-I_{B2} = 1.5 \text{mA}, V_{CE(ON)} = 0.25 \text{V}$
Fall Time	$t_{(f)}$	-	289	-	ns	
Storage Time	$t_{(\mathtt{s})}$	-	461	-	ns	$V_{CC} = 110V, I_{C} = 150mA,$
Fall Time	$t_{(f)}$	-	52	-	ns	$-I_{B2} = 1.5 \text{mA}, V_{CE(ON)} = 4V$

Notes: 5. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ 



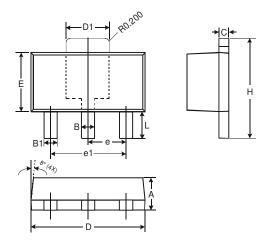


## **Typical Characteristics**



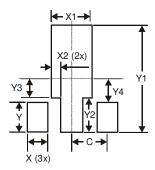


# **Package Outline Dimensions**



SOT89-3L			
Dim	Min	Max	
Α	1.40	1.60	
В	0.44	0.62	
B1	0.35	0.54	
С	0.35	0.43	
D	4.40	4.60	
D1	1.52	1.83	
Е	2.29	2.60	
е	1.50 Typ		
e1	3.00 Typ		
Н	3.94	4.25	
L	0.89	1.20	
All Dimensions in mm			

## **Suggested Pad Layout**



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500





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